



**Microsemi Corp.**  
The diode experts

SCOTTSDALE, AZ  
For more information call:  
(602) 941-6300

**1N759A, -1  
and  
1N4370 thru  
1N4372A, -1  
DO-35**

1% and 2% VERSIONS  
"C" and "D" AVAILABLE

**FEATURES**

- ZENER VOLTAGE 2.4V to 12.0V
- AVAILABLE IN JAN, JANTX AND JANTXV-1 QUALIFICATIONS TO MIL-S-19500/127. DIE ALSO AVAILABLE AS JANHC FOR HYBRIDS.
- METALLURGICALLY BONDED DEVICE TYPES

**MAXIMUM RATINGS**

Junction and Storage Temperatures: -65°C to +175°C  
DC Power Dissipation: 500 mW  
Power Derating: 4.0 mW/°C above 50°C  
Forward Voltage @ 200 mA: 1.5 Volts

**\* ELECTRICAL CHARACTERISTICS @ 25°C**

JEDEC TYPE NO. (NOTE 1)	NOMINAL ZENER VOLTAGE $V_Z$ @ $I_{ZT}$ (NOTE 2)	ZENER TEST CURRENT $I_{ZT}$	MAXIMUM ZENER IMPEDANCE $Z_Z$ @ $I_{ZT}$ (NOTE 3)	MAXIMUM REVERSE CURRENT @ $V_R = 1$ VOLT		MAXIMUM ZENER CURRENT $I_{ZM}$ (NOTE 4)	TYPICAL TEMP COEFF. OF ZENER VOLTAGE $(\alpha_{VZ})$
				@ 25°C	@ +150°C		
				$\mu A$	$\mu A$		
1N4370	2.4	20	30	100	200	150	-085
1N4371	2.7	20	30	75	150	135	-058
1N4372	3.0	20	29	50	100	120	-075
1N746	3.3	20	28	10	30	110	-066
1N747	3.6	20	24	10	30	100	-058
1N748	3.9	20	23	10	30	95	-046
1N749	4.3	20	22	2	30	85	-033
1N750	4.7	20	19	2	30	75	-015
1N751	5.1	20	17	1	20	70	$\pm 010$
1N752	5.6	20	11	1	20	65	+030
1N753	6.2	20	7	.1	20	60	+049
1N754	6.8	20	5	.1	20	55	+053
1N755	7.5	20	6	.1	20	50	+057
1N756	8.2	20	8	.1	20	45	+060
1N757	9.1	20	10	.1	20	40	+061
1N758	10.0	20	17	.1	20	35	+062
1N759	12.0	20	30	.1	20	30	+062

JEDEC Registered Data

**NOTE 1** Standard tolerance on JEDEC types shown is  $\pm 10\%$ . Suffix letter A denotes  $\pm 5\%$  tolerance; suffix letter C denotes  $\pm 2\%$ ; and suffix letter D denotes  $\pm 1\%$  tolerance.

**NOTE 2** Voltage measurements to be performed 20 sec. after application of D.C. test current.

**NOTE 3** Zener impedance derived by superimposing on  $I_{ZT}$ , a 60 cps, rms ac current equal to 10%  $I_{ZT}$  (2 mA ac).

**NOTE 4** Allowance has been made for the increase in  $V_Z$  due to  $Z_Z$  and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.

**SILICON  
500 mW  
ZENER DIODES**

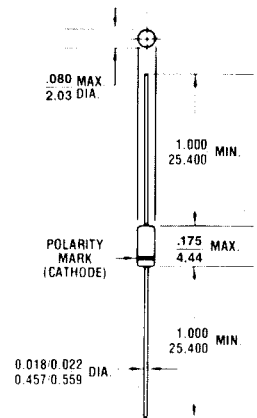


FIGURE 1

All dimensions in INCH  
m.m.

**MECHANICAL CHARACTERISTICS**

CASE: Hermetically sealed glass case. DO-35.

FINISH: All external surfaces are corrosion resistant and leads solderable.

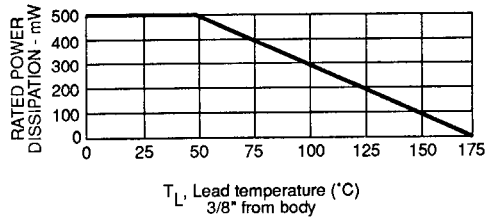
THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metallurgically bonded DO-35's exhibit less than 100 °C/W at zero distance from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

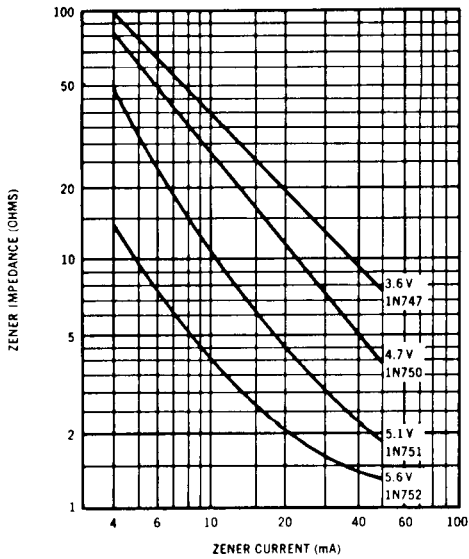
WEIGHT: 0.2 grams.

MOUNTING POSITIONS: Any.

**1N746 thru 1N759A, -1 DO-35**  
**1N4370 thru 1N4372A, -1**

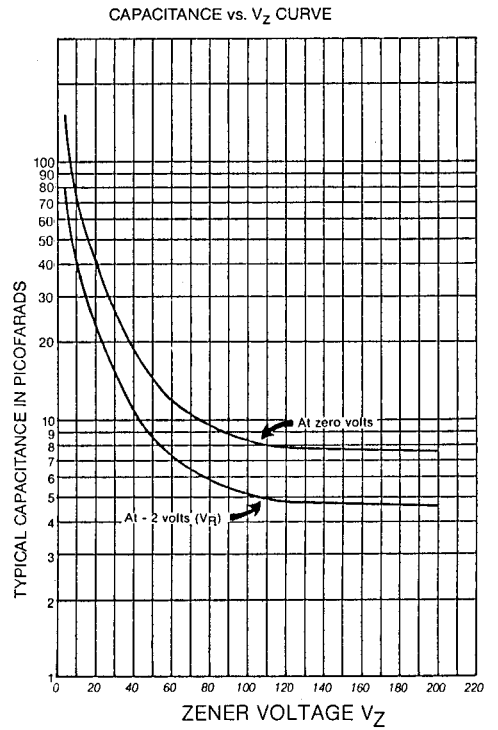


**FIGURE 2 POWER DERATING CURVE**



**FIGURE 3**

ZENER IMPEDANCE VS ZENER CURRENT  
(TYPICAL)



**FIGURE 4**

CAPACITANCE VS. ZENER VOLTAGE  
(TYPICAL)



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.